

L9916

Automotive multifunction alternator voltage regulator for 12 V / 24 V on board networks

Datasheet - production data

- Regulated voltage thermally compensated
- Configurable parameters through OTP cells
- Lamp driver (wake up and warning detection)
- Load response control (LRC)

Protections

- Thermal shutdown
- Field short circuit protection
- Protected high side relay driver

Features



Bare die

- AEC-Q100 qualified
- Fully monolithic design

Multiwatt8

- High side field driver
- Self-start function

Description

The L9916 is a smart alternator voltage regulator intended to be used in automotive application for both 12 V and 24 V systems. The presence of OTP cells for parameters programmability makes it suitable for a wide range of charging application.

Table 1. Device summary

Order code	Package	Packing		
L9916	Multiwatt8	Tube		
L9916BDTR	Bare die	Tape and Reel		

This is information on a product in full production.

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1 Functional description

The L9916 is an alternator voltage regulator with high side power output for field driving. It can be used in both 12 V and 24 V system. It supplies a current through a power high side MOSFET to the excitation coil of the alternator and provides an internal freewheeling diode.

The L9916 is suitable for multi-phase-current alternators and its target function is to keep the battery at its nominal value, whatever the vehicle demand is. The set point control is achieved using an internal voltage reference thermally compensated. Continuous feedback to the ECU is provided through the field monitor output.

Slew rate control and filtering of the interface lines provide electromagnetic compatibility.



Figure 1. Simplified application diagram

1.1 State diagram

The state diagram is a description of the L9916 possible working conditions.

Below it is represented a state diagram for L9916 describing its Operation Modes depending on the Speed Phase (RPM) applied to Phase pin (PH), the battery level on Battery pin (VB), the duty cycle applied by the device on Field pin (F), and the Alarm function status. Alarm function will turn-on the lamp in case of fault.

The states represented in the diagram are:

• Standby:

It is the reference state of the FSM. It's the starting state and the final state for any regulator operation cycle (turn-on, turn-off).

• Pre-excitation:

L9916 is ready to operate (when reached from standby), or it checks external conditions to move to a different state.



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Regulation:

L9916 is working in order to regulate the battery voltage to the required voltage set point VBSP.

• Phase regulation:

the L9916 controls the field driver to keep phase signal amplitude not falling below defined values.

LRC:

This state can be reached from Regulation in case there is a load variation that leads to meet some conditions on the expected field duty cycle value.

Crank:

This state is necessary to manage SDT (Start Delay Time) timer before entering normal regulation.

The assumptions considered in the below diagram are that the Self-start function is enabled and the wake-up source (IGN or Key) status is kept constant during the AVR working operation.

Colored tags define the condition for jumping to the next state and non-colored tags represent configurations.



Figure 2. State diagram

Note: LRC procedure firstly increases DF by DF_{LRCBZ} and then it continues slowly increasing the DF using a fixed slope DF_{LRCUP} After LRC is finished (due to VB = VBSP condition reached), the new regulation duty cycle DFreg will be DF' reached by the LRC procedure.

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1.2 Pin description

N°	PIN	Function					
1	PH	Phase sense input					
2	FM	Field Monitor (PWM signal going to ECU)					
3	IGN	ition input					
4	LAMP	ey sensing and Warning Lamp terminal output					
5	GND	Regulator ground					
6	SENSE	Remote battery sense input					
7	FIELD	High side driver output to control the Field current					
8	B+	Device power supply and Battery voltage sensing					

Tahlo	2	Pin	out	description
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Figure 3. Pin out diagram



1.3 External component required

The only component strictly required is the capacitor C1 (2.2 μ F suggested) to suppress radio frequency injection and has to be connected as close as possible to B and GND pins.

If in the application some pins are not used, it is recommended to connect them to ground directly or with a 10 nF capacitor.



2 Electrical specifications

2.1 Absolute maximum ratings

Table 3. Absolute maximum ratings	5
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Symbol	Parameter	Value	Unit
VB _{LD}	Transient supply voltage (load dump) t < 500 ms	58	V
VB _{MAX}	Transient supply voltage (low energy spikes) ISO7637-2 pulse 1,2,3 /ISO7637-3	58	V
Тj	Junction temperature range	-40 to 175	°C
T _{stg} , T _{case}	Storage and case temperature range	-40 to 150	°C
P _{TOT}	Total power dissipation (@ $T_{case} \le 150^{\circ}C$, $I_{field} \le 5 A$)	4	W
VB _R	Reverse battery voltage @ 25 °C, T = 15 sec	-2.5	V
VPH _{min}	Normal working condition reverse voltage (PH vs. GND)	-1.5	V
I _{Bond}	DC pin current on F, B, GND (bonding limitation)	15	А
ESD _{HBM}	ESD HBM (All pins vs.GND)	±4	kV

2.2 Internal clamping structure

Table 4. Internal clamping structure

_				1 0				
	#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
	1	V _{cl}	Internal central clamp voltage	B+ current injected I = 20 mA	58	-	64	V

Pin #	Pin name	ABS max rating		Operative range		Unit	
F111#		Min	Мах	Min	Мах	Unit	
1	PH	-25	Vcl	-3	36	V	
2	FM	-25	Vcl	-0.3	36	V	
3	IGN	-25	Vcl	-0.3	36	V	
4	LAMP	-0.3	B+	-0.3	36	V	
5	GND	-	-	-	-	-	
6	SENSE	-25	Vcl	-0.3	36	V	
7	FIELD	-1.5	B+	-1.5	B+	V	
8	B+	-2.5	Vcl	6	36	V	



2.3 Thermal data

Symbol	Parameter	Test condition / Note	Min	Тур	Мах	Unit		
R _{th_j-case}	Thermal resistance junction-to-case	Related to Multiwatt8	-	-	1.5	°C/W		
T _{j-sd}	Thermal shutdown threshold	Temperature to disable F, FM, L drivers.	160	175	190	°C		
T _{j-sdhy}	Thermal shut-down hysteresis	L, F, FM from OFF STATE (due to thermal shutdown) to ON STATE	T _{j-sd} -10	-	T _{j-sd} -2	°C		
		-	-40	-	150			
Тj	Operation temperature	Fully functional. Parameter Deviations permissible	150	-	T _{j-sd}	°C		

Table 6. Thermal data

2.4 Electrical characteristics

 T_i = -40 to 150 °C, unless otherwise specified.

2.4.1 Pin "B"

The L9916 is supplied by the B+. This voltage is also used as the feedback voltage by the regulation loop.

#	Symbol	Parameter	arameter Test condition / Note		Тур	Max	Unit		
1	VB _{OVR}	Operating Voltage Range	Application info, refer to Figure 7	6	-	36	V		
2	IB _{stby}	Standby current consumption 12 V			-	120	μA		
3	IB _{stby}	Standby current consumption 12 V	VB = 12.5 V; VPH = 0; VL = 0 V; VIGN = open; VSENSE = 12.5 V T = 25°C	-	-	170	μA		
4	IB _{stby}	Standby current consumption 24 V	VB = 24 V; VPH = 0; VL = 0 V; VIGN = open; VSENSE = 0 V T = 25 °C	-	-	160	μA		
5	IB _{stby}	Standby current consumption 24 V	VB = 24 V; VPH = 0; VL = 0 V; VIGN = open; VSENSE = 24 V T = 25 °C	-	-	200	μA		
6	IB _{active}	Current consumption out of standby	VB = 12.5 V; VSENSE = 12.5 V VB = 24 V; VSENSE = 24 V No current load on FIELD and LAMP	5	11	30	mA		

Table 7.	Electrical	characteristics	- Pin "B"
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#	Symbol	Parameter	Parameter Test condition / Note		Тур	Мах	Unit	
7	VB _{SP12,1}				13.5			
8	VB _{SP12,2}				13.6			
9	VB _{SP12,3}				13.7			
10	VB _{SP12,4}				13.8			
11	VB _{SP12,5}				13.9			
12	VB _{SP12,6}		VPH=10 Vpp square wave; L pin		14			
13	VB _{SP12,7}				14.1			
14	VB _{SP12,8}	Set-point voltage	connected to B pin with	-0.15	14.2	+0.15	v	
15	VB _{SP12,9}	12 V Option	100 ohm; @ T _j = 30 °C F duty cycle = 50%	-0.15	14.3	+0.15	v	
16	VB _{SP12,10}		F duty cycle = 50%		14.4			
17	VB _{SP12,11}				14.5			
18	VB _{SP12,12}				14.6			
19	VB _{SP12,13}	-				14.7		
20	VB _{SP12,14}					14.8		
21	VB _{SP12,15}				14.9	-		
22	VB _{SP12,16}				15			
23	VB _{SP24,1}				27	-		
24	VB _{SP24,2}				27.2			
25	VB _{SP24,3}				27.4			
26	VB _{SP24,4}				27.6			
27	VB _{SP24,5}				27.8			
28	VB _{SP24,6}				28			
29	VB _{SP24,7}		VPH=20 Vpp square wave; L pin		28.2			
30	VB _{SP24,8}	Set-point voltage	connected to B pin with	-0.25	28.4	+0.25	v	
31	VB _{SP24,9}	24 V Option	100 ohm; @ Tj=30°C	-0.25	28.6	+0.25		
32	VB _{SP24,10}		F duty cycle=50%		28.8			
33	VB _{SP24,11}]			29			
34	VB _{SP24,12}				29.2			
35	VB _{SP24,13}]			29.4			
36	VB _{SP24,14}]			29.6			
37	VB _{SP24,15}]			29.8			
38	VB _{SP24,16}				30			

Table 7. Electrical characteristics - Pin "B" (continued)





#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
39	VB _{ITD1}		-		0		
40	VB _{ITD2}	Internal Thermal	-	4(40)()	-2.5	. 1 (10) ()	mV/°C
41	VB _{ITD3}	Drift Options	-	-1(12 V)	-3.5	+1(12 V)	
42	VB _{ITD4}	30°C <t<150°c< td=""><td>-</td><td>-2(24 V)</td><td>-7</td><td>+2(24 V)</td><td></td></t<150°c<>	-	-2(24 V)	-7	+2(24 V)	
43	VB _{ITD5}		-		-10		
39bis	VB _{ITD1}		-		0		
40bis	VB _{ITD2}	Internal Thermal	-	0(10.)()	-2.5		
41bis	VB _{ITD3}	Drift Options	-	-2(12 V)	-3.5	+2(12 V)	mV/°C
42bis	VB _{ITD4}	-40°C <t<30°c< td=""><td>-</td><td rowspan="2">-4(24 V)</td><td>-7</td><td>+4(24 V)</td><td></td></t<30°c<>	-	-4(24 V)	-7	+4(24 V)	
43bis	VB _{ITD5}		-		-10		
44	$\Delta VB_{load,1}$	Regulated Voltage variation with the load 12 V (24 V) system	Difference between regulated voltage when F duty cycle is 10% and regulated voltage when F duty cycle is 90%	-	-	200 (300)	mV
45	ΔVB _{load,2}	Regulated Voltage variation with the load 12 V (24 V) system	Difference between regulated voltage when F duty cycle is 10% and regulated voltage when F duty cycle is 90%	-	-	300 (400)	mV
46	ΔVB _{speed} (1)	Regulated Voltage variation with the speed 12 V (24 V)	Difference between regulated voltage when I _{gen} = 10 A 2000rpm <alt speed<18000rpm<="" td=""><td>-</td><td>-</td><td>100 (150)</td><td>mV</td></alt>	-	-	100 (150)	mV
47	VBwb12 ⁽¹⁾	Regulation without battery 12 V system	I _{alt} = 5 A resistive; T _{case} = 25 °C; 2000 < rpm < 18000	12	-	16	V
48	VBwb24 ⁽¹⁾	Regulation without battery 24 V system	I _{alt} = 5 A resistive; T _{case} = 25 °C; 2000 < rpm < 18000	22	-	34	V
49	VB _{SP_CL12}	Set Point Voltage clamp at low temperature (-40°C) F duty cycle=50% 12 V system	-	14.7	15	15.3	V
50	VB _{SP_CL24}	Set Point Voltage clamp at low temperature (-40 °C) F duty cycle = 50% 24 V system	-	28.4	29	29.6	V

Table 7. Electrical characteristics - F	Pin	"B"	(continued)
		_	(001101000)

1. Alternator dependent parameter not tested.





Figure 5. Application 12 V - Default setpoint with -3.5 mV/°C



Regulation Curves Versus Temperature @ F Duty Cycle = 50% (Example with VBSP=14.5V, VBITD=-3.5mV/°C)



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Figure 6. Application 24 V - Default setpoint with -3.5 mV/°C

Regulation Curves Versus Temperature @ F Duty Cycle = 50% (Example with VBSP=29V, VBITD=-3.5mV/°C).

Cranking security function

In order to avoid unpredictable regulation regions during the engine start, the regulator implements a Cranking Security Function.

At the ignition key on (i.e. "key" switch closed in the application schematic) the device starts in pre-excitation; in this phase the battery voltage is over both VB_{UV} and VB_{LOW} and the pin F provides a fixed duty cycle. When the starter is engaged, the battery sources a big current and then the applied voltage on the device decreases, as reported in ISO 7637-1 pulse 4 specification. If the voltage on pin B decreases under VB_{LOW} threshold then the device will be frozen: the device will be in low current consumption with no activity on both F and FM pins.

The device will remain in frozen conditions until the voltage on B overcomes the VB_{low} threshold. After that the device start again to evaluate the input coming from PH pin.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
1	VB _{Ovp12V}	Over-voltage protections threshold 12 V system	-	16		16.9	V
2	VB _{Ovp24V}	Over-voltage protections threshold 24 V system	-	32	33	34	V
3	VB _{OVft}	Over-voltage filter time	-	0.5	1.25	2	ms
4	VB _{UV12V}	Under Voltage 12 V system	-	8	9	10	V
5	VB _{UV24V}	Under Voltage 24 V system	-	16	18	20	V

Table 8. VB over and under voltage parameters



#	Symbol Parameter		Test condition / Note	Min	Тур	Max	Unit	
6	VBlow	Low Voltage	-	5.6	6.35	7	V	
7	VBLV _{filt}	Low-voltage filter time	Guaranteed down to VB _{low}	100	150	200	us	

Table 8. VB over and under voltage parameters (continued)

Overvoltage

For safety reason this function is implemented with independent circuitry with respect to the ones used by the field driver in order to guarantee that in case of overvoltage the field driver is securely switched off.

Undervoltage

When detected the L9916 switches on the lamp.

Low voltage

When detected the L9916 enters in stand by condition. All drivers are OFF including the lamp driver.



Figure 7. VB over and under voltage



2.4.2 Pin "SENSE"

The system battery can be directly sensed using the SENSE input. If the voltage on SENSE pin goes below the SENSE_{disc} threshold a sense disconnection is detected. If voltage of B+ is SENSE_{diff} greater than voltage of SENSE, the L9916 will use the B+ value to control the set point voltage, otherwise use SENSE voltage.

The device detects a 'sense loss' when either the sense disconnection or the voltage difference comparator is active.

It's possible to select if the voltage setpoint is increased by 1 V in case of sense loss.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Мах	Unit	
1	SENSE _{disc,12}	Sense disconnected when	-	7.5	8.5	9.5	V	
2	SENSE _{disc,24}	Sense voltage is below	-	11	12	13	V	
3	SENSE _{diff,1}	Voltage difference	-	1.2	1.6	2.1	V	
4	SENSE _{diff,2}	(B+) - Sense	-	1.8	2.3	2.9	V	
5	Delta VB _{SP}	Voltage setpoint increase in case of SENSE loss	-	0.9	1	1.1	V	
6	Filter time S to B+	Digital filter time to switch from S to B+ regulation	-	0.8	1	1.2	ms	
7	Filter time B+ to S	Digital filter to switch from B+ to S regulation	-	160	200	240	ms	
8	I _{SENSE_PD}	Pull down current	-	10	45	80	μA	

 Table 9. Electrical characteristics - Pin "SENSE"



2.4.3 Pin "IGN"

The IGN pin is an input that can be used to wake-up the device in place of the Lamp and the selection is performed by OTP. The usage of one wake-up input (L or IGN) excludes the other one. The signal applied to IGN is compared to a threshold VIGNON and VIGNOFF and the result is used to turn the device on. If not used this pin must be left open.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Мах	Unit		
1	VIGN _{ON}	Voltage threshold input comparator to switch on	-	6	8	10	V		
2	VIGN _{OFF}	Voltage threshold input comparator to switch off	-	1.3	1.6	1.9	V		
3	VIGN _{OFFHYS}	Voltage threshold input comparator to go in logic state = High Z	-	VIGN _{OFF} +0.25	VIGN _{OFF} +0.35	VIGN _{OFF} +0.45	V		
4	R _{pu}	Pull-up resistance	-	26	52	80	kΩ		

Table 10. Electrical characteristics - Pin "IGN"



Figure 8. Pin "IGN" diagrams

2.4.4 Wake-up behaviour

In this chapter it is described the device wake-up behaviour depending on the signal on IGN, L, PH pin and the selection between Mode1 and Mode2 done through OTP programming.

The device wakes-up through L pin or IGN pin.

- The IGN input pin is able to read 3 level voltages (see Figure 8), the below values for IGN Note: are intended as follows:
 - 1 = input voltage higher then $VIGNIT_{ON}$
 - $0 = input voltage lower then VIGNIT_{OFF}$

High-Z = input voltage between $VIGNIT_{OFF}$ and $VIGNIT_{ON}$



IGN input not used (see Section 2.4.3).

IGN	L	PH	Regulator					
Х	0	Not present	OFF					
Х	0	Present	ON					
X	1	Not present	ON					
X	1	Present	ON					

Table 11. Self-start function enabled

IGN input not used (see Section 2.4.3).

Table 12	Self-start	function	disabled
		ranouon	algabica

IGN	L	РН	Regulator
Х	0	Not present	OFF
X	0	Present	OFF
X	1	Not present	ON
Х	1	Present	ON

In case of condition L = 1, PH = present, regulator = ON the L signal becomes = 0, the regulator goes in OFF condition.

IGN input used (see Section 2.4.3).

Table 13. Self-start function enabled (Mode 1)

IGN	L	РН	Regulator
0	Х	Х	OFF
1	Х	Х	ON
High-Z	Х	Not present	OFF
High-Z	Х	Present	ON

IGN input used (see Section 2.4.3).

Table 14	. Self-start	function	disabled	(Mode 1)	١
		Tunotion	albubica		,

IGN	L	РН	Regulator
0	Х	Х	OFF
1	Х	Х	ON
High-Z	Х	Not present	OFF
High-Z	Х	Present	OFF

IGN input used (see Section 2.4.3).

Table 15. Self-start function enabled (Mode 2)

IGN	L	РН	Regulator
0	Х	Not present	OFF
0	Х	Present	ON



IGN	L	РН	Regulator					
1	Х	Х	ON					
High-Z	Х	Not present	OFF					
High-Z	Х	Present	ON					

Table 15. Self-start function enabled (Mode 2) (continued)

Note: X = Don't care.

2.4.5 Pin "FM"

The pin Field Monitor is used to communicate to the ECU the information about the activity on the field.



Figure 9. Pin "FM" circuit and waveform

Table 16. Electrical characteristics - Pin "FM"

#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
1	VM _{LVS}	Low voltage saturation	I-sink = 14 mA	0.9	1.2	1.5	V
2	fM _{SW,1}	Field monitor frequency switch Option1	-	-	fF _{SW}	-	Hz
	fM _{SW,2}	Field monitor frequency switch Option2	Not available if the Field switching freq = 125 Hz	-	fF _{SW} /2	-	Hz
3	DM _{DCR}	Field monitor duty cycle range	In case of duty cycle clamp selected	5	-	95	%
4	IM _{lim}	Field monitor current limitation	-	25	50	75	mA
5	T _{lim}	Duration of current limitation	-	50	-	100	μs
6	TF _{retry}	Retry time in case of over- current	Orer-sument Threatool Betry line	30	40	50	ms
7	I _{leak_FM}	Leakage current	-	-	-	3	μA



The Field Monitor switching frequency can be selected to be the same as the field driver switching frequency or one half of it, using the OTP cells

The polarity of the Field Monitor signal can be selected "direct" or "reverse" respect to the field driver signal, using the OTP cells

The duty cycle of the Field Monitor signal can be selected to have maximum and minimum values of 95% and 5% in case the field signal has a duty cycle higher than 95% or lower than 5%, using the OTP cells.

In case of short to VB the current output is limited to IM_{lim} for a time equal to T_{lim} then the output is switched off and turned on again after TF_{retrv} .

The duty cycle presented on FM is a replica, of a frequency depending on the OTP selection, of the duty cycle into the Field in order to provide to the ECU the information of the load connected to the alternator.

The duty cycle presented on FM is different from the signal on the Field in the following cases:

In the pre-excitation state FM always it has a fixed duty cycle equal to DFPreex (12.5%) whatever the battery voltage is.

When the device exits the pre-excitation, for all the time in which the phase regulation is active, on pin FM a signal with a duty cycle of 6% is presented. If the phase regulation persists over time the device continues to show a 6% duty cycle. Elapsed the phase regulation, the duty cycle of FM becomes equal to the duty cycle on the Field.

In the following requests of phase regulation, the Field executes the request while the FM continues to send the information of the entity of the current load. The activation of the field needed to implement the phase regulation is excluded from the account of the duty cycle: for example, if the battery voltage rises above the set point as a consequence of a load disconnection and a phase regulation is required, the field executes while FM continues to have a duty cycle of 0% (or its clamp value) that is the real load on the alternator in that moment.



2.4.6 Pin "PH"

The PH pin is the input for the phase signal coming from the alternator.

The VP_{HTh}, VP_{LTh} are the voltage thresholds for the phase input detection used when the L pin or the IGN pin is connected. In case of self-start there are 4 couples of thresholds that can be selected and that are used for the first turn-on, once the speed exceeds the SPSS, x threshold the device will switch to the VP_{HTh}, VP_{LTh} thresholds.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
1	VP _{HTh}	High voltage threshold of hysteresis input buffer in case L or IGN connected and after self-start	-	1.3	1.45	1.6	V
2	VP _{LTh}	Low voltage threshold of hysteresis input buffer in case L or IGN connected and after self-start	-	0.85	1	1.15	V
3	VP _{HTh_SS1}	High voltage threshold of hysteresis input buffer for self-start switch-on	-	0.25	0.37	0.45	V
4	VP _{LTh_SS1}	Low voltage threshold of hysteresis input buffer for self-start switch-on	-	0.15	0.24	0.35	V
5	VP _{HTh_SS2}	High voltage threshold of hysteresis input buffer for self-start switch-on	-	0.6	0.76	0.9	V
6	VP _{LTh_SS2}	Low voltage threshold of hysteresis input buffer for self-start switch-on	-	0.35	0.45	0.6	V
7	VP _{HTh_SS3}	High voltage threshold of hysteresis input buffer for self-start switch-on	-	1.1	1.22	1.35	V
8	VP _{LTh_SS3}	Low voltage threshold of hysteresis input buffer for self-start switch-on	-	0.85	1	1.15	V
9	VP _{HTh_SS4}	High voltage threshold of hysteresis input buffer for self-start switch-on	-	1.3	1.45	1.6	V
10	VP _{LTh_SS4}	Low voltage threshold of hysteresis input buffer for self-start switch-on	-	0.85	1	1.15	V
11	RP _{pd}	Pull-down resistor (in addition to IP _{pull-dw})	-	7	15	22	kΩ
12	TP _{SR}	Spike rejection time	-	70	125	180	us
13	IP _{pull-dw}	Pull-down current (in addition to RP _{pd})	-	1.5	2	3.5	mA

Table 17. Electrical characteristics - Pin "PH"



Table 17. Electrical characteristics - Pin "PH" (continued)									
#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit		
14	SP _{HPrex,1}	High rpm Threshold to exit pre-excitation Option1 ⁽¹⁾	-	Typ-10%	900	Typ+10%			
15	SP _{HPrex,2}	High rpm Threshold to exit pre-excitation Option2 ⁽¹⁾	-	Typ-10%	1200	Typ+10%	505		
16	SP _{HPrex,3}	High rpm Threshold to exit pre-excitation Option3 ⁽¹⁾	-	Typ-10%	1500	Typ+10%	rpm		
17	SP _{HPrex,4}	High rpm Threshold to exit pre-excitation Option4 ⁽¹⁾	-	Typ-10%	1800	Typ+10%			
18	SP _{HYS}	Speed hysteresis	-	Typ-10%	200	Typ+10%	rpm		
19	SP _{LPrex}	Low speed threshold to enter pre excitation	-	SPF	SP _{HPrex} - SPHYS				
20	SP _{SS,1}		-	Typ-10%	1200	Typ+10%			
21	SP _{SS,2}		-	Typ-10%	1500	Typ+10%			
22	SP _{SS,3}	options ⁽¹⁾	-	Typ-10%	2800	Typ+10%	rpm		
23	SP _{SS,4}		-	Typ-10%	3200	Typ+10%			
24	SP _{LRC,1}		-	Typ-10%	1500	Typ+10%			
25	SP _{LRC,2}	rpm Threshold to exit/enter	-	Typ-10%	2800	Typ+10%	rom		
26	SP _{LRC,3}	in LRC options	-	Typ-10%	3000	Typ+10%	rpm		
27	SP _{LRC,4}		-	Typ-10%	3200	Typ+10%			
28	VP _{prHTh12V}	High phase regulation voltage threshold 12 Vapp	-	6.7	7.7	8.7	V		
29	VP _{prLTh12V}	Low phase regulation voltage threshold 12 Vapp	-	3	4	5	V		
30	VP _{prHTh24V}	High phase regulation voltage threshold 24 Vapp	-	14	15.5	17	V		
31	VP _{prLTh24V}	Low phase regulation voltage threshold 24 Vapp	-	5.2	6.2	7.2	V		
32	TP _{OFF}	Max windows time to detect 4 phase periods	-	57	64	71	ms		

Table 17. Electrical characteristics - Pin "PH" (continued)

1. Recommended: $SP_{SS} \ge SP_{HPrex}$.

To convert phase frequency (Hz) to rotation speed (rpm) according to alternator poles pair number (N), use the following equation:

rotation speed (rpm) = phase frequency (Hz) * 60 / N (rpm spread: ± 10%)

Principle of phase regulation

When VB is above the set-point voltage, the field driver is controlled to keep the phase peak voltage from falling below VP_{prTh} . If the phase peak voltage drops below VP_{HTh} , the phase regulation does not work. During the Phase regulation the field is driven with a fixed duty-cycle and frequency, $T_{on} = 40$ ms and $T_{off} = 40$ ms. If during the T_{on} phase the VP_{prTh} threshold is reached the field is switched off even if the 40 ms have not elapsed.



The phase regulation is performed in both cases, either the high level phase signal does not cross the VP_{pTh} threshold or the low level phase signal does not cross the VP_{LTh} threshold.



Figure 10. Phase regulation in case VPH signal does not cross VP_{prTh}





L9916



2.4.7 Pin "F"

The pin F is the output of the high side PowerMOS used to drive the field load.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit	
1	Ron	Ron field driver	T _j = 130 °C; I _{sunk} = 4.5 A			130	mΩ	
2	VF _{diode}	Freewheeling diode	I _{sourced} = 5 A	-2			V	
3	IF _{leak}	Field leakage current	VB = 50 V; VF = 0	-5		5	μA	
			T _j = -40 °C	9		18	А	
4	IF _{OVP}	Field driver over- current protection	T _j = 25 °C	8.5		18	А	
			T _j = 130 °C	8		18	А	
5	I _{ocft}	Over-current filter time	-	2.5	5	7.5	μs	
5	TF _{retry}	Retry time in case of over-current	Over-current Threahold Retry time	30	40	50	ms	
6	VF _{ONdet}	Voltage threshold ON-state detection	-	0.9	1.1	1.3	V	
7	fF _{SW,1}		-	-10%	125	+10%		
8	fF _{SW,2}	Field switching	-	-10%	250	+10%	Hz	
9	fF _{SW,3}	frequency options	-	-10%	333	+10%	1 IZ	
10	fF _{SW,4}		-	-10%	400	+10%		
11	T _{fall}	Voltage slew rate for field driver (Measurement is performed between 80% and 20% of the slope	VB = 14 V R = 270 Ω	1	4	10	μs	
12	T _{rise}	Voltage slew rate for field driver (Measurement is performed between 20% and 80% of the slope)	VB = 14 V R = 270 Ω	1	4	10	μs	
13	DF _{Preex}	Field duty cycle in pre-excitation	-	11	12.5	14	%	
14	DF _{SS}	Field duty cycle in self start	Applied when only "ph" signal is present and speed< SP _{SS}	4	6	8	%	



#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
15	TF _{LRCUP,1}		-	2.12	2.5	2.88	
16	TF _{LRCUP,2}		-	2.55	3	3.45	
17	TF _{LRCUP,3}		-	4.25	5	5.75	
18	TF _{LRCUP,4}	Load Response	-	5.1	6	6.9	
19	TF _{LRCUP,5}		-	6.37	7.5	8.63	S
20	TF _{LRCUP,6}		-	7.65	9	10.35	
21	TF _{LRCUP,7}		-	8.5	10	11.5	
22	TF _{LRCUP,8}		-	10.2	12	13.8	
23	DF _{LRCUP}	Positive Duty Cycle vs. time variation	-	10	0 / TF _{LRC}	CUP	%/s
24	TF _{LRCDW}	Load Response Control Time (100% to 0% DC)	- TF _{LRCUP} * 3 / 8			S	
25	DF _{LRCDW}	Negative Duty Cycle vs. time variation	-	- 100 / TF _{LRCDW}		CDW	%/s
26	DF _{LRCEnab}	Current vs. Previous Duty Cycle Variation to Enable LRC Function (internal duty cycle sampled every 1ms)	-	4.1	6.7	9.2	%
27	DF _{LRCBZ}	Blind Zone	Test conditions:Battery:VB = SetPoint - 0.3;SDT:DisabledKey/Ignition:Key-ON (VIGN ≥ VIGNON)Phase:VPH ≥ VPRHTTest:RPM change from SPLPrex -100 to SPHPrex +100;F Duty-cycle has to change from 12.5% to 12.5%+BZ;	2.6	5.3	7.8	%
	TF _{SDT,1}		-	0.4	0.5	0.6	
20	TF _{SDT,2}	Start Delay Time	-	2.12	2.5	2.88	
28	TF _{SDT,3}	options	-	4.25	5	5.75	S
	TF _{SDT,4}	1	-	8.5	10	11.5	

Table 18. Electrical characteristics - Pin "F" (continued)



Self-start function

In case no other wake up source is detected except the phase signal the device wakes up by self-start. During the self-start phase, the device will apply the DF_{SS} field duty cycle on the field if the speed is < SP_{SS} . Above SP_{SS} the device will work with the normal regulation.

Load response control function (LRC)



Figure 12. Load response control function (LRC)

When an electrical load is applied in the system application, a drop in the regulated voltage (VB) occurs and the alternator reacts by increasing the output current. If the LRC function is active then the alternator output current is controlled by the Field current variation strategy, that is directly linked to the duty cycle on Field signal.

The LRC function can operate when the alternator runs at low speed (the PH signal frequency has to be lower than fP_{LRC}) and it is activated when a positive variation between current duty cycle on Field and its previous duty cycle values is higher than the DF_{LRCEnab}. When the LRC function is required, the duty cycle increases slowly with the defined slope DF_{LRCUP} starting from the previous duty cycle increased by the fixed value DF_{LRCBZ}. The actual duty cycle management during a LRC insertion is shown in the *Figure 12*. Once the LRC function is started it completes the required ramp even if the alternator speed becomes higher than the SP_{LRC}.



2.4.8 Pin "L"

The L pin is used to detect the key presence and to drive the warning lamp. It can also drive an optional relay for auxiliary loads.



Figure 13. Pin "L" circuit diagram

The L pin is used to drive the fault indicator lamp and the optional auxiliary load relay.

The device exits the stand-by mode when the switch "Key" is closed (i.e. VL>VL_{HTh}).

The Lamp is driven by an internal low side N-channel MOSFET whereas the relay is driven by an internal high-side N-channel MOSFET.

The current in Low side driver is limited to IL_{IimLS} for a time TL_{OC} , then the driver is switched off. After T_{retry} the low side driver is turned on again.

To reduce the power dissipation in the lamp driver while it is ON, the following strategy is implemented: after key-on, as soon as the L pin voltage overcomes VL_{th}, after T_{filter} time it is brought to VL_{sat} voltage (between its drain and source), then the key status is verified every T_{wait} time intervals within a T_{chk} time window.

During this window, if the key is switched on the L voltage reaches the VL_{HTh} value and immediately returns to the VL_{sat} value before the window expiration whereas, if the key is no longer active, the L voltage cannot increase and remains below key detection threshold (VL_{HT}).





Figure 14. Pin "L" waveform diagrams



The high side driver is switched off if the current overcomes the $\rm IL_{\rm OVCHS}$ for $\rm T_{\rm LH\ filter}$ time.

#	Symbol	Parameter	Test condition / Note	Min	Тур	Мах	Unit			
1	VL _{SAT}	Lamp Driver saturation Voltage	I _{sunk} =300 mA	-	-	0.3	v			
2	R _{onL}	Ron Lamp driver	T _j = 175 °C; I _{sunk} = 300 mA	-	-	1	Ω			
3	I _{pulldw}	Pull down current	-	0.6	1	1.4	mA			
4	T _{filt}	Key-on filter time	-	-	40	-	μs			
5	T _{chk}	Key presence check time window	Digital window time	-	-	1	ms			

Table 19. Electrical characteristics - Pin "L"



#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
6	T _{wait}	Key presence interval	-	34	40	46	ms
7	VL _{HTh}	High Voltage Threshold key- ON detector	-	0.8	0.9	1	v
8	IL _{limLS,12V}	LS current limitation threshold	-	1.2	-	2.4	А
9	IL _{limLS,24V}	LS current limitation threshold	-	0.6	-	1.2	A
10	TL _{delay}	Turn ON delay time	-	-	-	100	us
11	TL _{OC}	Maximum time duration of linear current limitation	Over-current Threshold	-	30	35	ms
12	TL _{retry}	Retry time in case of over- current duration > TL _{OC}	Current limitation time Retry time	510	600	690	ms
13	VH _{sat}	Relay Driver saturation Voltage	V(B+)=12.6V; I _{sourced} =0.3A	-		1	v
14	Ron _{HS}	Ron HS relay driver	T _j =175°C; I _{source} =300mA	-	-	3	Ω
15	IL _{OVCHS}	HS Over- current threshold	-	1	-	2	А
16	TL _{HSretry}	Retry time in case of over- current	-	30	40	50	ms
17	TL _{Hfilter}	HS Over current filter time	-	_	5	-	μs
18	TL _{alarm,1}		-	0.42	0.5	0.58	
19	TL _{alarm,2}	Alarm	-	0.85	1	1.15	
20	TL _{alarm,3}	validation time	-	1.27	1.5	1.73	S
21	TL _{alarm,4}		-	1.7	2	2.3	

Table 19. Electrical characteristics - Pin "L" (continued)

Note: In case Lamp Driver exceeds safety temperature, it will be turned OFF,



2.5 Alarm detection

The device turns ON the lamp after the validation time (TL_{alarm}) if one of the conditions in the below table is verified.

Detection condition	Related pin/ Description	Configurable
VPH< VP_{prTh} and VB < VB_{SP}	F driver or its connection degraded	No
IF>IF _{OVP}	F shortened to GND (Over-current on F driver)	No
VB>VB _{SP} and VF>VF _{ONdet}	F shortened to B	No
VB>VB _{Ovp12V} VB>VB _{Ovp24V} ⁽¹⁾	Battery sensor on B pin or F driver degraded	No
VB <vb<sub>UV</vb<sub>	Low B Voltage (Battery under-voltage)	No
VSENSE< SENSE _{disc}	SENSE connection loss	Yes
VIGNIT _{OFF} <vign< vignit<sub="">ON</vign<>	VIGN open	Yes

1. In case of IGN interface enabled with self-start function enabled, if the IGN pin is in High_z (Mode 1 and Mode 2) or at 0 level (only mode 2), the lamp and relay drivers are disabled if an overvoltage occurs.

In case of VPH<VPHTh or PH frequency < f_{PLPrex} the device enters in pre-excitation state and turns ON the lamp.

Also during self start when SPHprex<PH<SPss the device will enters in wakeup mode and turn on the lamp.

2.6 End of line test mode

Through the FM pin the device can enter a special "test mode" where some time consuming functions are not present.

The functions that are not present are:

LRC, SDT and TL_{alarm}

To enter the "test mode" it is necessary to bring the FM pin voltage to V_{FM_TM} and the device must not be in overvoltage condition (VB> VBO_{vp}).

#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
1	V _{FM_TM}	Voltage threshold to enter in EOL test mode	-	37	41	45	V

 Table 21. End of line test mode

2.7 OTP programming

The programming of the device parameters is achieved by using the I²C interface which is implemented on two pins (PH and DFM) having also such alternative functions.

Here below some general information on the I²C



The L9916 is I^2C slave device, so SCL (clock line from I^2C Master device) is input, while SDA (data line) is bidirectional to allow transmit/receive operations to/from I^2C master device. Both SCL and SDA lines are connected to a positive power supply voltage via pull-up resistor. The I^2C protocol defines the proper operations of the link. When the bus is free, both lines are High (pulled-up). The output stages of the devices connected to the bus must have an open-drain or open-collector to perform the wired-AND function. The maximum link rate is 400 kbit/s.

The required voltage for the OTP programming is 15.7 V±0.5 V.

For the programming procedure refer to the dedicated document.



Figure 15. I²C interface circuit

Table 22. OTP programming	electrical characteristics
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#	Symbol	Parameter	Test condition / Note	Min	Тур	Max	Unit
1	f _{SCL}	Clock frequency	-	10		400	kHz
2	VIL	Input low voltage	-			1.5	V
3	VIH	Input high voltage	-	2.3			V

2.7.1 External pull up resistor sizing

Given:

 C_p = wiring (line) capacitance

- f = Target frequency
- R_p = Pull up resistor

T = 1/f

⊤ = Time constant

and assuming that for proper operation T < T/4, if the target frequency (SCL) is 100 kHz and the line capacitance is $C_p = 100 \text{ pF}$ we got:

 $T = 1/f = 10 \ \mu s$

 τ = Rp*Cp < T/4 = 2.5 ms => Rp < 2.5 ms/100 pF = 25 k Ω



3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

3.1 Multiwatt 8 (pin 5 GND) package information



Figure 16. Multiwatt 8 (pin 5GND) package outline



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	Dimensions						
Ref	Millimeters			Inches ⁽¹⁾			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	-	-	5	-	-	0.1969	
В	-	-	2.65	-	-	0.1043	
С	-	-	1.6	-	-	0.0630	
Е	0.49	-	0.55	0.0193	-	0.0217	
F	0.78	-	0.85	0.0307	-	0.0335	
G	2.40	2.54	2.68	0.0945	0.1000	0.1055	
G1	17.64	17.78	17.92	0.6945	0.7000	0.7055	
H1	19.6	-	-	0.7717	-	-	
H2	-	-	20.2	-	-	0.7953	
L	20.35		20.65	0.8012		0.8130	
L2	17.05	17.20	17.35	0.6713	0.6772	0.6831	
L3	17.25	17.5	17.75	0.6791	0.6890	0.6988	
L4	10.3	10.7	10.9	0.4055	0.4213	0.4291	
L7	2.65	-	2.9	0.1043	-	0.1142	
S	1.9	-	2.6	0.0748	-	0.1024	
S1	1.9	-	2.6	0.0748	-	0.1024	
U	0.40	-	0.55	0.0157	-	0.0217	
Z	0.70	-	0.85	0.0276	-	0.0335	
diam1	3.65	-	3.85	0.1437	-	0.1516	

Table 23. Multiwatt 8 (pin 5GND) package mechanical drawing

1. Values in inches are converted from mm and rounded to 4 decimal digits.



3.2 Multiwatt 8 marking information



Figure 17. Multiwatt 8 marking information

Parts marked as 'ES' are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.



4 Revision history

Date	Revision	Changes
20-Apr-2016	1	Initial release.
13-Jun-2016	2	Modified on the <i>Table 7: Electrical characteristics - Pin "B"</i> the test conditions for " Δ VB _{load,1} and Δ VB _{load,2} " parameter. Modified on the <i>Table 8: VB over and under voltage parameters</i> the values for "VB _{OVIt} " parameter. Updated: <i>Figure 2: State diagram on page 6;</i> <i>Figure 8: Pin "IGN" diagrams on page 16.</i>
21-Aug-2017	3	 Updated: Sections: Section 1.3: External component required on page 7, Section 2.1: Absolute maximum ratings on page 8, Section 2.4: Electrical characteristics on page 9, Section 2.5: Alarm detection on page 29. Figures: Figure 4: Regulated Voltage variation with the load on page 12, Figure 5: Application 12 V - Default setpoint with -3.5 mV/°C on page 12, Figure 6: Application 24 V - Default setpoint with -3.5 mV/°C on page 13, Figure 7: VB over and under voltage on page 14, Figure 8: Pin "IGN" diagrams on page 16, Figure 14: Pin "L" waveform diagrams on page 27. Tables: Table 1: Device summary on page 1 Table 3: Absolute maximum ratings on page 8, Table 6: Thermal data on page 9; Table 6: Thermal data on page 9; Table 7: Electrical characteristics - Pin "B" on page 13, Table 10: Electrical characteristics - Pin "IGN" on page 16, Table 11: Device and under voltage parameters on page 13, Table 12: Electrical characteristics - Pin "B" on page 9; Table 13: Electrical characteristics - Pin "IGN" on page 16, Table 10: Electrical characteristics - Pin "F" on page 20, Table 13: Electrical characteristics - Pin "F" on page 23, Table 19: Electrical characteristics - Pin "L" on page 23,

Table 24. Document	revision	history
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